



isc Silicon NPN Power Transistors

DESCRIPTION

- · Collector-Emitter Breakdown Voltage-
 - : V_{(BR)CEO}= 160V(Min)
- · High Power Dissipation-
 - : P_C= 125W(Max)@T_C=25°C
- · Complement to Type 2SB656
- Minimum Lot-to-Lot variations for robust device performance and reliable operation

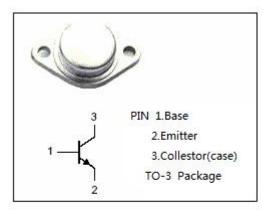
APPLICATIONS

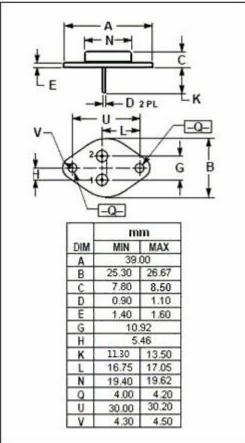


• Designed for low frequency power amplifier applications.

ABSOLUTE MAXIMUM RATINGS(T_a=25℃)

| SYMBOL | PARAMETER | VALUE | UNIT |
|------------------|---|-------|------------|
| V _{СВО} | Collector-Base Voltage | 160 | V |
| V _{CEO} | Collector-Emitter Voltage | 160 | V |
| V _{EBO} | Emitter-Base Voltage | 5 | V |
| lc | Collector Current-Continuous | 12 | Α |
| Ісм | Collector Current-Peak | 20 | Α |
| Pc | Collector Power Dissipation @T _C =25℃ | 125 | W |
| TJ | Junction Temperature | 150 | $^{\circ}$ |
| T _{stg} | Storage Temperature -55~150 | | $^{\circ}$ |







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2SD676

ELECTRICAL CHARACTERISTICS

Tj=25℃ unless otherwise specified

| SYMBOL | PARAMETER | CONDITIONS | MIN | TYP. | MAX | UNIT |
|----------------------|--------------------------------------|--|-----|------|-----|------|
| V _{(BR)CEO} | Collector-Emitter Breakdown Voltage | I _C = 10mA; R _{BE} = ∞ | 160 | | | V |
| V _{(BR)EBO} | Emitter-Base Breakdown Voltage | I _E = 1mA; I _C = 0 | 5 | | | V |
| V _{CE(sat)} | Collector-Emitter Saturation Voltage | I _C = 6A; I _B = 0.6A | | | 2.5 | V |
| V _{BE(on)} | Base-Emitter On Voltage | I _C = 1A; V _{CE} = 5V | | | 1.5 | V |
| Ісво | Collector Cutoff Current | V _{CB} = 140V; I _E = 0 | | | 1 | mA |
| h _{FE-1} | DC Current Gain | I _C = 1A; V _{CE} = 5V | 60 | | 200 | |
| h _{FE-2} | DC Current Gain | I _C = 6A; V _{CE} = 5V | 20 | | | |

♦ h_{FE-1} Classifications

| В | С | | |
|--------|---------|--|--|
| 60-120 | 100-200 | | |

NOTICE:

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